

Abstract Submitted  
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**Computational Design of Photovoltaic Materials with Self Organized Nano Structures** KAZUNORI SATO, Graduate School of Engineering Science, Osaka University and PRESTO-JST, HIROSHI KATAYAMA-YOSHIDA, Graduate School of Engineering Science, Osaka University — Chalcopyrite and II-VI semiconductors, such as  $\text{Cu}(\text{In}, \text{Ga})\text{Se}_2$ ,  $\text{Cu}_2\text{ZnSn}(\text{S}, \text{Se})_4$  and  $\text{Cd}(\text{S}, \text{Te})$ , are one of the most promising materials for low cost photovoltaic solar-cells. In this paper, based on first-principles calculations, we propose that self-organized nano-structures in these compounds will enhance the conversion efficiency. Our calculations are based on the KKR-CPA-LDA [1] with the self-interaction correction [2]. We also use VASP package [3] for calculating mixing energy and effective interactions of the systems by using the cluster expansion method [4]. For phase separating systems, we simulate nano-structure formation by using the Monte Carlo method. It is expected that the photo-generated electron-hole pairs are efficiently separated by the type-II interface and then effectively transferred along the quasi-one-dimensional structures. Moreover, we can expect multiplication of generated carriers due to the multi-exciton effects in nano-structures [5].

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Kazunori Sato  
Graduate School of Engineering Science,  
Osaka University and PRESTO-JST

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